L Number	Hits	Search Text	DB	Time stamp
1	200	(hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 11:29
2	54	((hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.) and (sic or silicon adj carbide)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08
3	8	((hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.) and (sic or silicon adj carbide) and attach\$6	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 11:33
4	93	(sic or silicon adj carbide) and attach\$6 near5 coefficient	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08
5	15	(sic or silicon adj carbide) same attach\$6 near5 coefficient	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 11:49
6	919	(sic or silicon adj carbide) and 117/84-109.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 11:49
7	130	(sic or silicon adj carbide) and 117/89.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08
8	53	(sic or silicon adj carbide) and 117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane))	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08
9	22	(sic or silicon adj carbide) and 117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 11:52
10	10	117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 13:14
11	60	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08
12	0	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 13:16
13	1	alternat\$5 117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same cycl\$5	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/08 13:16
14		117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same period\$5	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:17

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15	120	//gia on -ilidi manhido) and	HCDAM.	2004/07/00
12	128	((sic or silicon adj carbide) and	USPAT;	2004/07/08
		117/84-109.ccls.) and source and cycle	US-PGPUB;	14:50
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
16	10	sccm near10 (silicon or carbon) and (sic	USPAT;	2004/07/08
		or silicon adj carbide) and	US-PGPUB;	15:48
		117/84-109.ccls.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
17	13	attach\$4 near3 coefficient and	USPAT;	2004/07/08
		117/84-109.ccls.	US-PGPUB;	15:48
			EPO; JPO;	ļ
			DERWENT;	
			IBM TDB	
18	73	puls\$4 same (deposit\$4 or growth) same	USPĀT;	2004/07/08
		(silicon adj carbide or sic) not laser	US-PGPUB;	15:48
			EPO; JPO;	
			DERWENT;	
			IBM TDB	